

TEMIC

Siliconix

SD211DE/SST211 Series**N-Channel Lateral DMOS FETs**

SD211DE	SST211
SD213DE	SST213
SD215DE	SST215

Product Summary

Part Number	V _{(BR)DS} Min (V)	V _{GS(th)} Max (V)	r _{DS(on)} Max (Ω)	C _{rss} Max (pF)	t _{ON} Max (ns)
SD211DE	30	1.5	45 @ V _{GS} = 10 V	0.5	2
SD213DE	10	1.5	45 @ V _{GS} = 10 V	0.5	2
SD215DE	20	1.5	45 @ V _{GS} = 10 V	0.5	2
SST211	30	1.5	50 @ V _{GS} = 10 V	0.5	2
SST213	10	1.5	50 @ V _{GS} = 10 V	0.5	2
SST215	20	1.5	50 @ V _{GS} = 10 V	0.5	2

For applications information see AN301, page 33.

Features

- Ultra-High Speed Switching—t_{ON}: 1 ns
- Ultra-Low Reverse Capacitance: 0.2 pF
- Low Guaranteed r_{DS} @ 5 V
- Low Turn-On Threshold Voltage
- N-Channel Enhancement Mode

Benefits

- High Speed System Performance
- Low Insertion Loss at High Frequencies
- Low Transfer Signal Loss
- Simple Driver Requirement
- Single Supply Operation

Applications

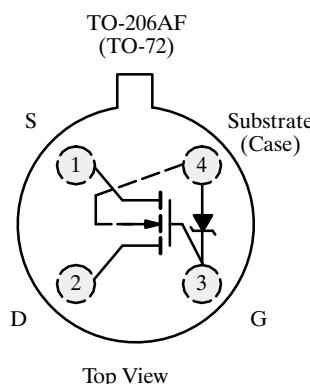
- Fast Analog Switch
- Fast Sample-and-Holds
- Pixel-Rate Switching
- DAC Deglitchers
- High-Speed Driver

Description

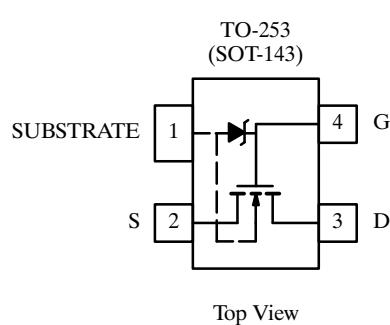
The SD211DE/SST211 series consists of enhancement-mode MOSFETs designed for high speed low-glitch switching in audio, video, and high-frequency applications. The SD211 may be used for ± 5 -V analog switching or as a high speed driver of the SD214. The SD214 is normally used for ± 10 -V analog switching. These MOSFETs utilize lateral construction to achieve low capacitance and

ultra-fast switching speeds. An integrated Zener diode provides ESD protection. These devices feature a poly-silicon gate for manufacturing reliability.

For similar products see: quad array—SD5000/5400 series and non-Zener protection—SD210DE/214DE.



SD211DE, SD213DE, SD215DE



SST211 (D1)*, SST213 (D3)*, SST215 (D5)*

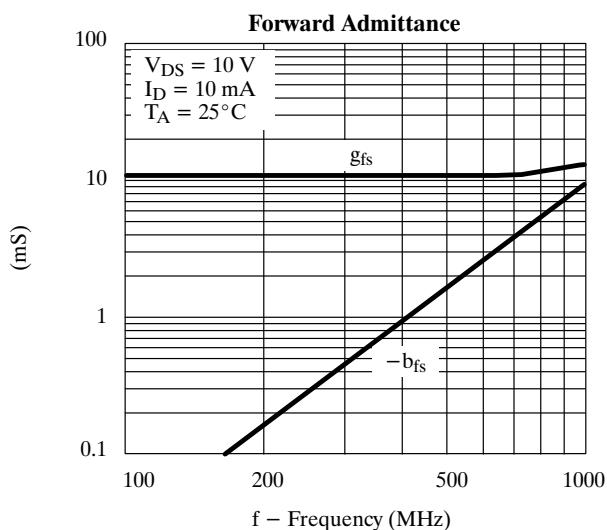
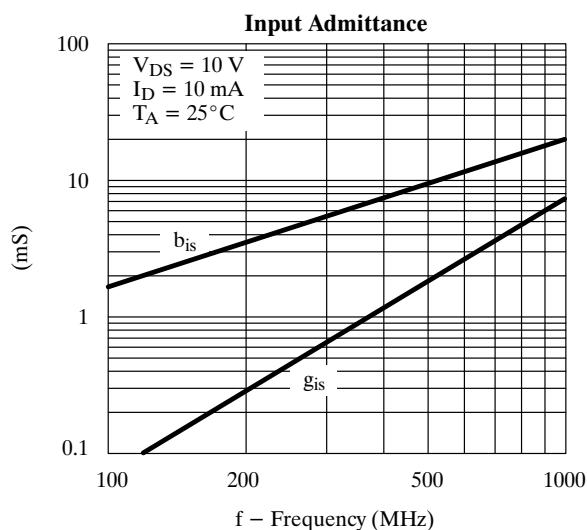
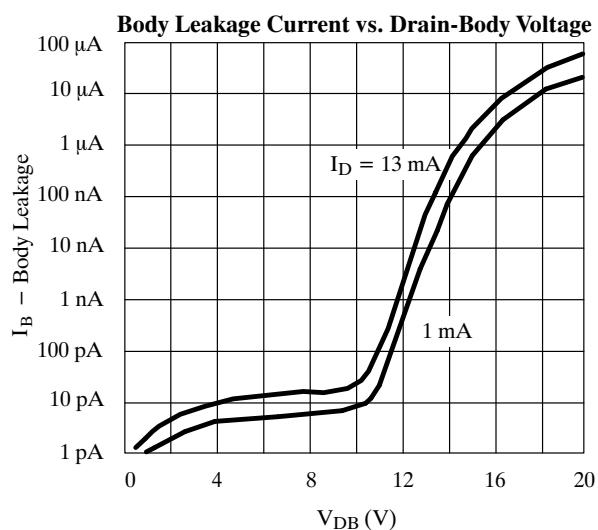
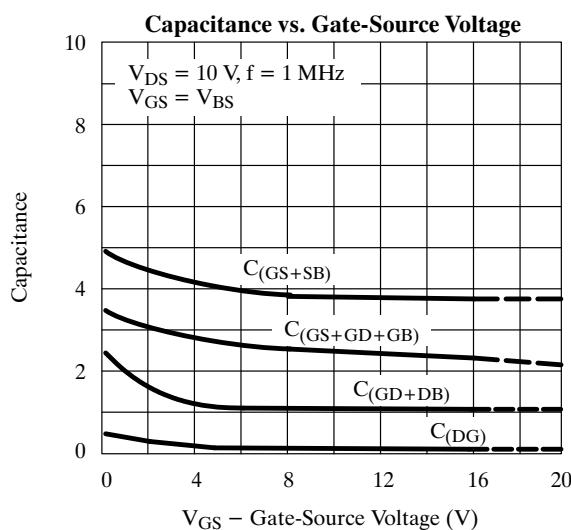
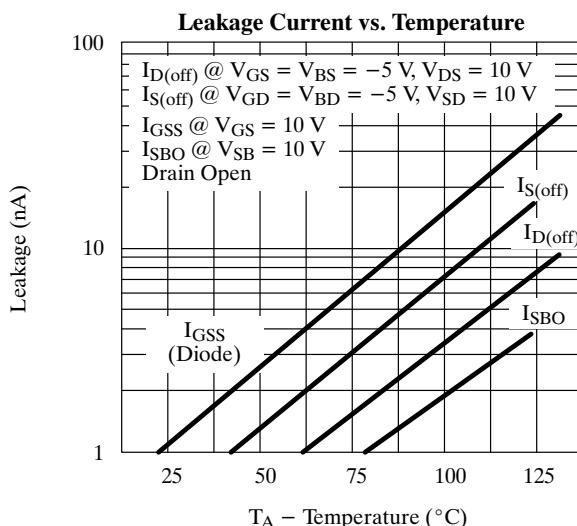
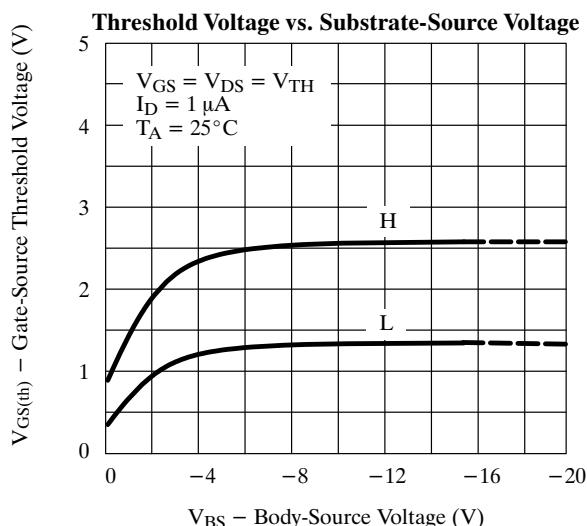
*Marking Code for TO-253

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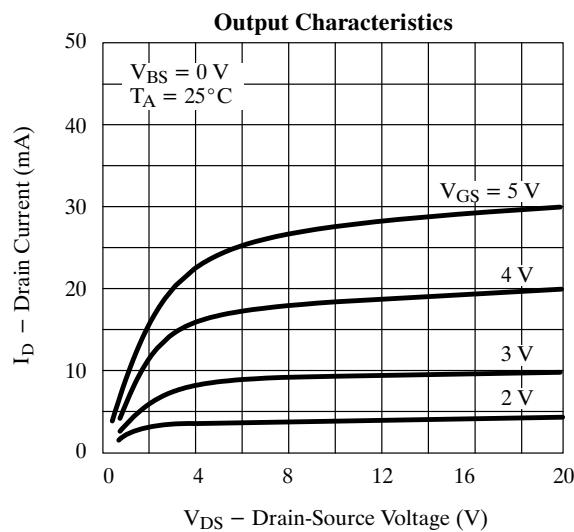
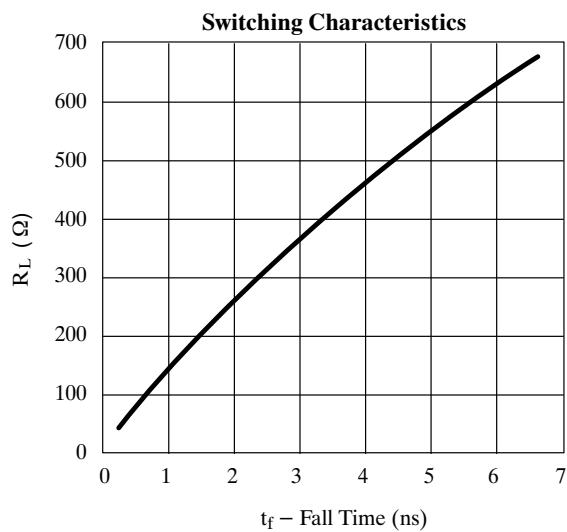
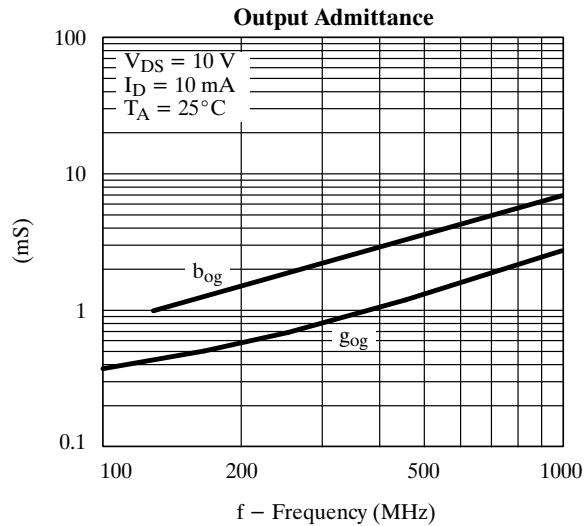
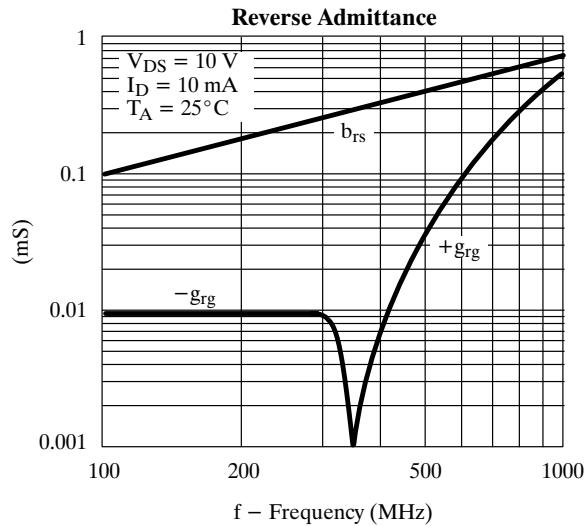
SD211DE/SST211 Series

Typical Characteristics (Cont'd)



SD211DE/SST211 Series

Typical Characteristics



Switching Time Test Circuit

